



30V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage 30 V Current 0.6A

Features

- RDS(ON), VGS@4,5V, ID@0.6A<220mΩ
- RDS(ON), VGS@2.5V, ID@0.4A<290mΩ
- RDS(ON), VGS@1.8V, ID@0.1A<600mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

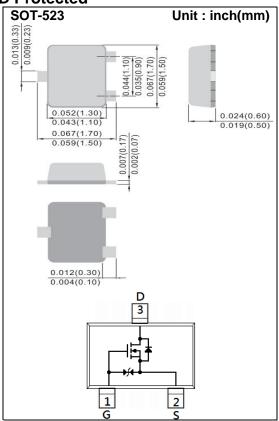
Mechanical Data

• Case: SOT-523 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.00007 ounces, 0.002 grams

Marking: E04



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	0.6	Α
Pulsed Drain Current		I _{DM}	2.4	Α
Power Dissipation	T _a =25°C	P _D	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	417	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.5	0.79	1.3	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =0.6A	-	177	220	mΩ	
		V_{GS} =2.5V, I_{D} =0.4A	-	223	290		
		V _{GS} =1.8V, I _D =0.1A	-	330	600		
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} =30V, V_{GS} =0V	-	0.01	1	uA	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	<u>+</u> 1.5	<u>+</u> 10	uA	
Dynamic (Note 5)							
Total Gate Charge	Q_g	V _{DS} =15V, I _D =0.6A, V _{GS} =4.5V ^(Note 1,2)	-	1.5	-	nC	
Gate-Source Charge	Q_gs		-	0.3	-		
Gate-Drain Charge	Q_{gd}		-	0.3	-		
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1.0MHZ	-	93	-	pF	
Output Capacitance	Coss		-	19	-		
Reverse Transfer Capacitance	Crss		-	6	-		
Turn-On Delay Time	td _(on)	V_{DD} =15V, I_{D} =0.6A, V_{GS} =4.5V, R_{G} =6 Ω (Note 1,2)	-	6	-		
Turn-On Rise Time	tr		-	33	-	ns	
Turn-Off Delay Time	td _(off)		-	37	-		
Turn-Off Fall Time	tf	R _G =012	-	32	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	I _S		-	-	0.4	А	
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.81	1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

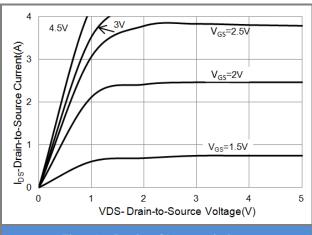


Fig.1 On-Region Characteristics

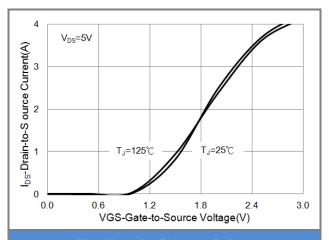


Fig.2 Transfer Characteristics

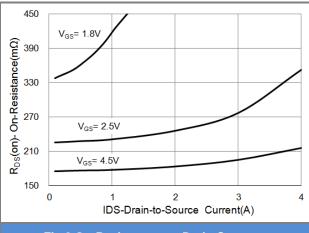


Fig.3 On-Resistance vs. Drain Current

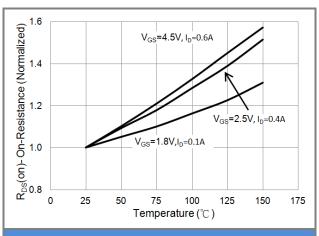
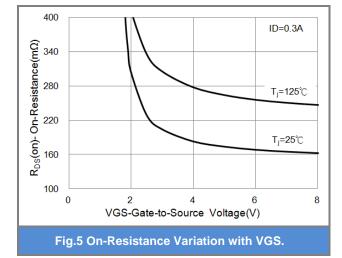
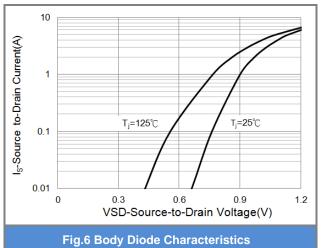


Fig.4 On-Resistance vs. Junction temperature





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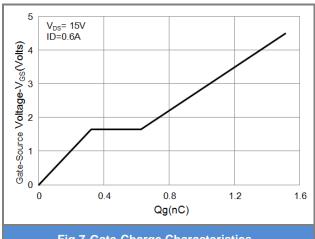


Fig.7 Gate-Charge Characteristics

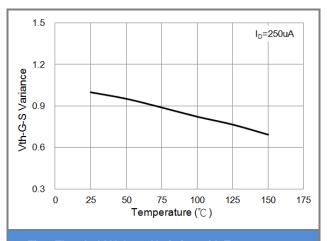


Fig.8 Threshold Voltage Variation with Temperature.

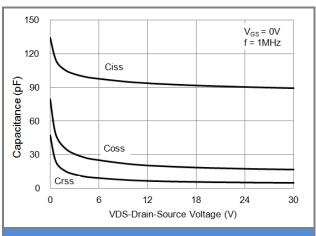


Fig.9 Capacitance vs. Drain-Source Voltage.

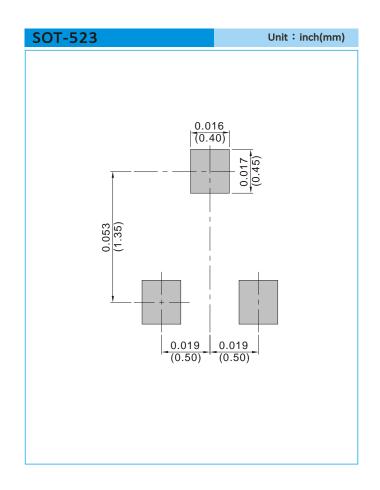




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJE8404_R1_00001	SOT-523	4K pcs / 7" reel	E04	Halogen free

MOUNTING PAD LAYOUT







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